HFB16HY20C

PD-94222C

Ultrafast, Soft Recovery Diode
Thru-Hole (TO-257AA)
200V, 16A

Features

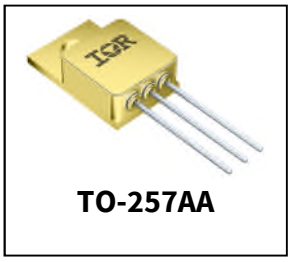
- Single device configuration
- Reduced RFI and EMI
- Reduced snubbing
- Extensive characterization of recovery parameters
- Hermetically sealed
- Ceramic eyelets
- ESD Rating: Class 3B per MIL-STD-750, Method 1020

Product Summary

- **V_R :** 200V
- **V_F:** 1.17V
- **t_{rr} :** 50ns
- **$di_{(rec)M}/dt$:** 360A/µs

Potential Applications

- DC-DC converter
- Motor drives



TO-257AA

Product Validation

Qualified according to MIL-PRF-19500 for space applications

Description

HEXFRED™ diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and di/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motor drives and other applications where switching losses are significant portion of the total losses.

Ordering Information

Table 1 Ordering options

Part number	Package	Screening Level
HFB16HY20C	TO-257AA	COTS
HFB16HY20CSCX	TO-257AA	JANTX-equivalent
HFB16HY20CSCS	TO-257AA	S-level

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1 Absolute Maximum Ratings

Table 2 Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_R	Cathode to anode voltage	200	V
$I_{F(AV)}$	Continuous forward current, T_C = 120°C [1]	16	A
I_{FSM}	Single pulse forward current, T_C = 25°C [2]	140	A
P_D @ T_C = 25°C	Maximum power dissipation	100	W
T_J T_{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
Wt	Weight	4.3 (Typical)	g

[1] DC = 50% rectangle wave

[2] ½ sine wave, 60 Hz, Pulse width = 8.33 ms

2 Device Characteristics

2.1 Electrical Characteristics

Table 3 Electrical Characteristics @ T_J =25°C (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
V_{BR}	Cathode Anode Breakdown Voltage	200	—	—	V	I_R = 100µA
V_F	Forward Voltage Drop See Fig. 1	—	—	1.29	V	I_F = 16A, T_J = -55°C
		—	—	1.17	V	I_F = 16A, T_J = 25°C
		—	—	1.52	V	I_F = 32A, T_J = 25°C
		—	—	1.48	V	I_F = 32A, T_J = 125°C
I_R	Reverse Leakage Current See Fig. 2	—	—	10	µA	V_R = V_R Rated
		—	—	200	µA	V_R = V_R Rated, T_J = 125°C
C_J	Junction Capacitance See Fig. 3	—	—	200	pF	V_R = 200V
L_S	Series Inductance	—	9.8	—	nH	Measured from anode lead to cathode lead, 6mm (0.025 in) from package

2.2 Dynamic Recovery Characteristics

Table 4 Dynamic Recovery Characteristics @ T_J =25°C (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions	
t_{rr1}	Reverse Recovery Time See Fig. 5	—	42	50	ns	T_J = 25°C	I_F = 16A
t_{rr2}		—	61	—		T_J = 125°C	
I_{RRM1}	Peak Recovery Current See Fig. 6	—	4.6	—	A	T_J = 25°C	V_R = 160V
I_{RRM2}		—	8.4	—		T_J = 125°C	
Q_{rr1}	Reverse Recovery Charge See Fig. 7	—	105	—	nC	T_J = 25°C	di_f/dt = 200 A/ µs
Q_{rr2}		—	280	—		T_J = 125°C	
$di_{(rec)M}/dt_1$	Peak Rate of Fall of Recovery Current During t_b See Fig. 8	—	360	—	A/ µs	T_J = 25°C	
$di_{(rec)M}/dt_2$		—	685	—		T_J = 125°C	

2.3 Thermal-Mechanical Characteristics

Table 5 Thermal-Mechanical Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JC}$	Junction to Case, See Fig. 4	—	1.25	°C/W

3 Electrical Characteristics Curves

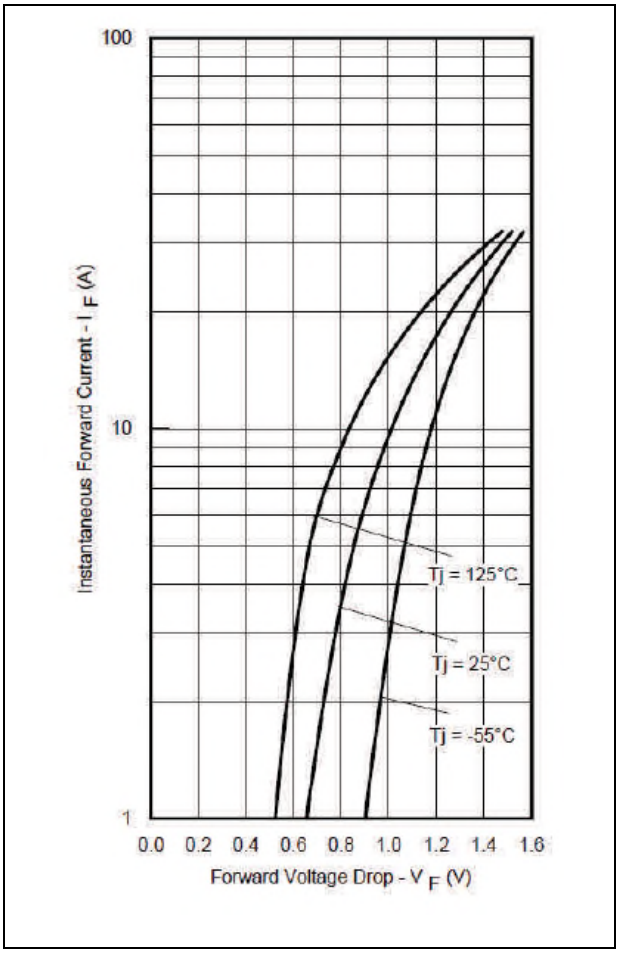


Figure 1 Maximum Forward Voltage Drop Characteristics

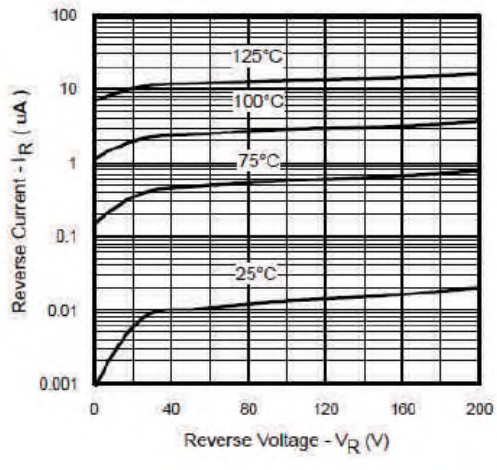


Figure 2 Typical Values of Reverse Current Vs. Reverse Voltage

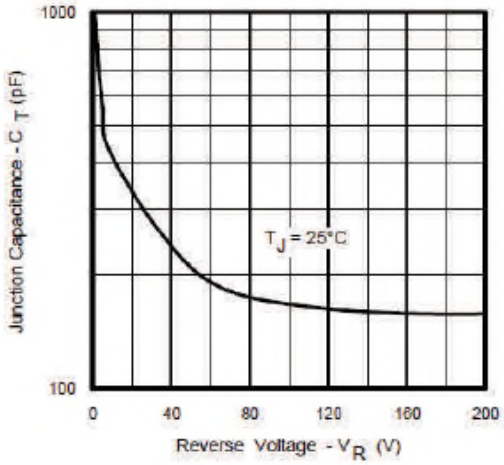


Figure 3 Typical Junction Capacitance Vs. Reverse Voltage

Electrical Characteristics Curves

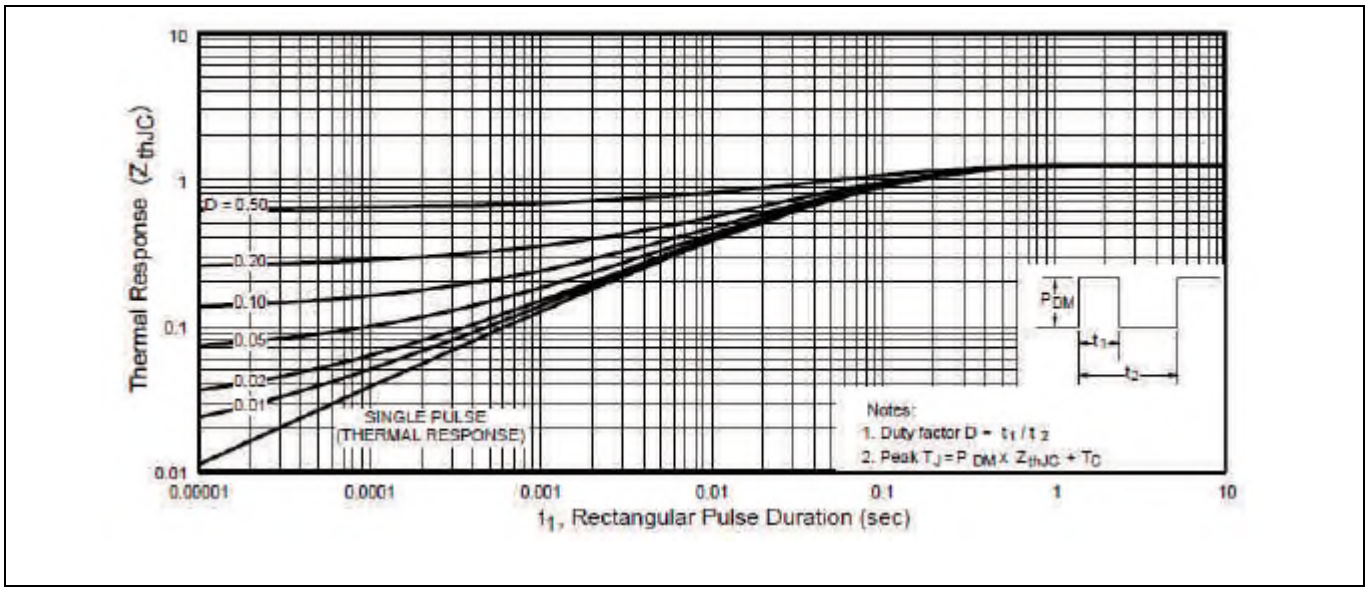


Figure 4 Maximum Thermal Impedance Z_{thJC} Characteristics

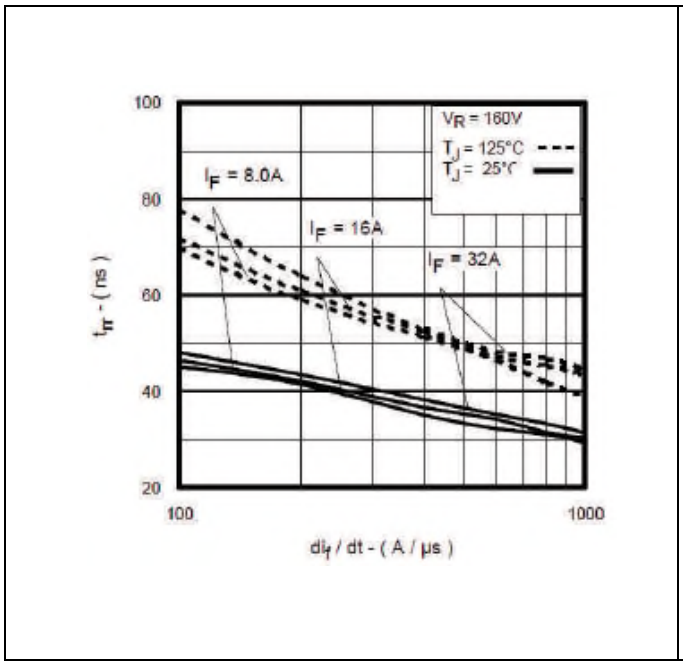


Figure 5 Typical Reverse Recovery Vs. di_f/dt

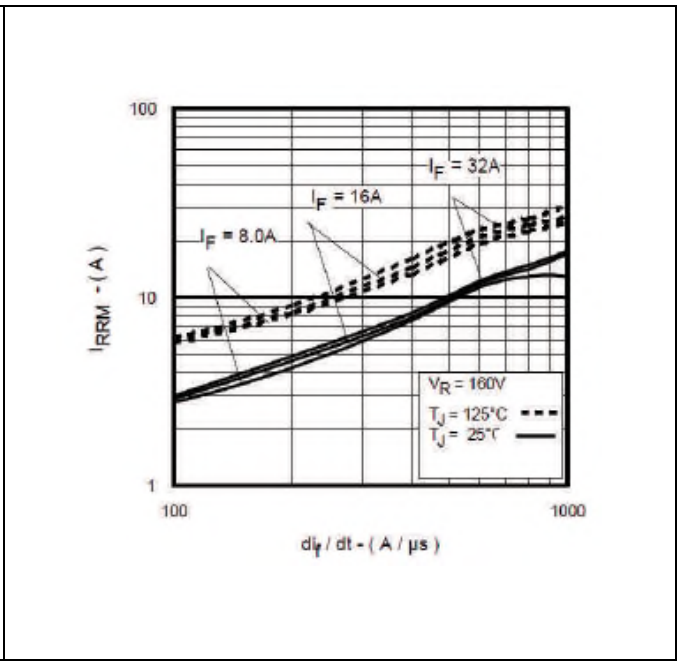


Figure 6 Typical Recovery Current Vs. di_f/dt

Electrical Characteristics Curves

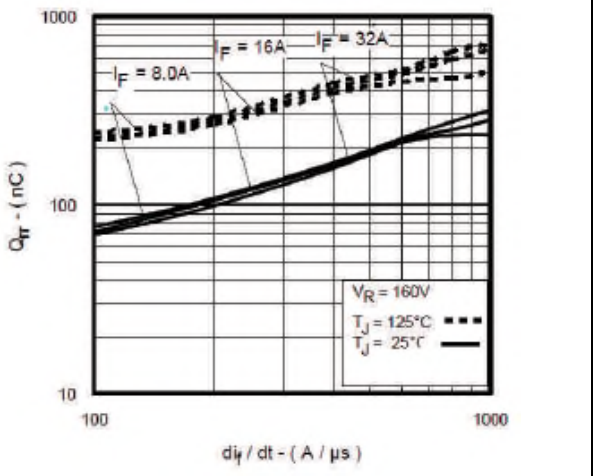


Figure 7 Typical Stored Charge Vs. di_f/dt

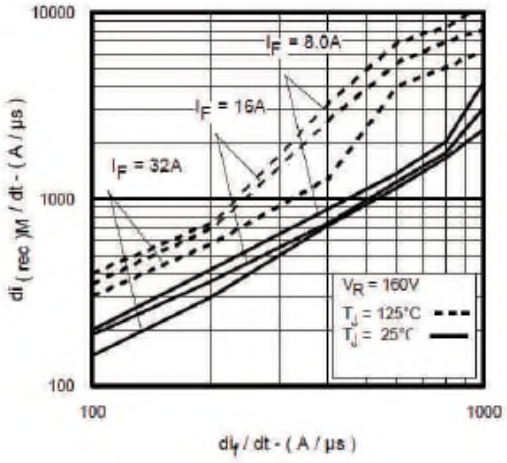


Figure 8 Typical $di_{(rec)M}/dt$ Vs. di_f/dt

4 Test Circuit

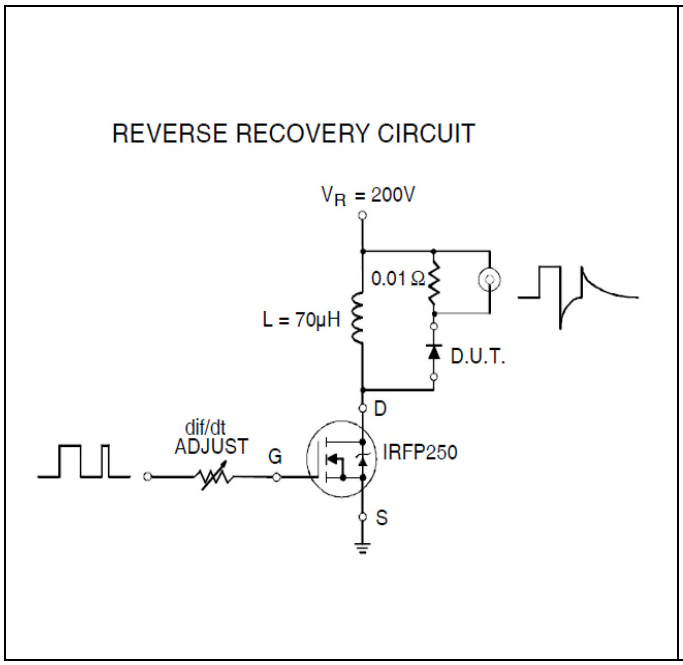


Figure 9 Reverse Recovery Parameter Test Circuit

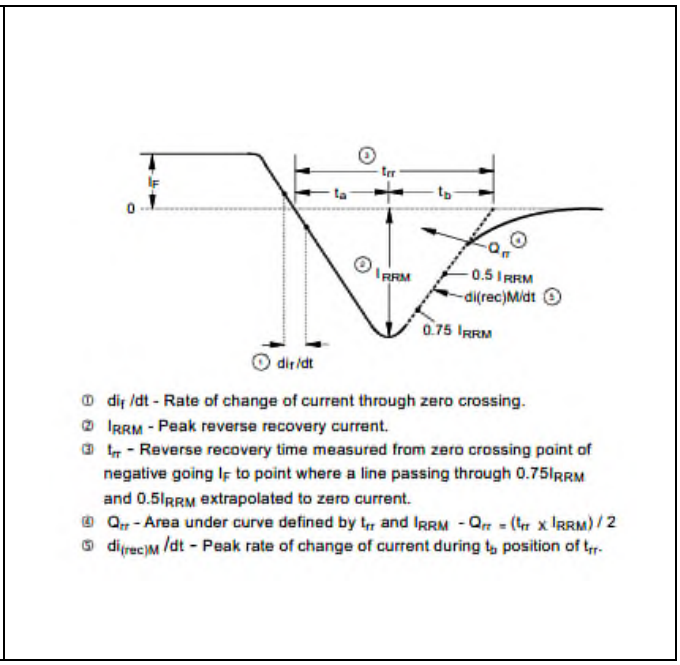
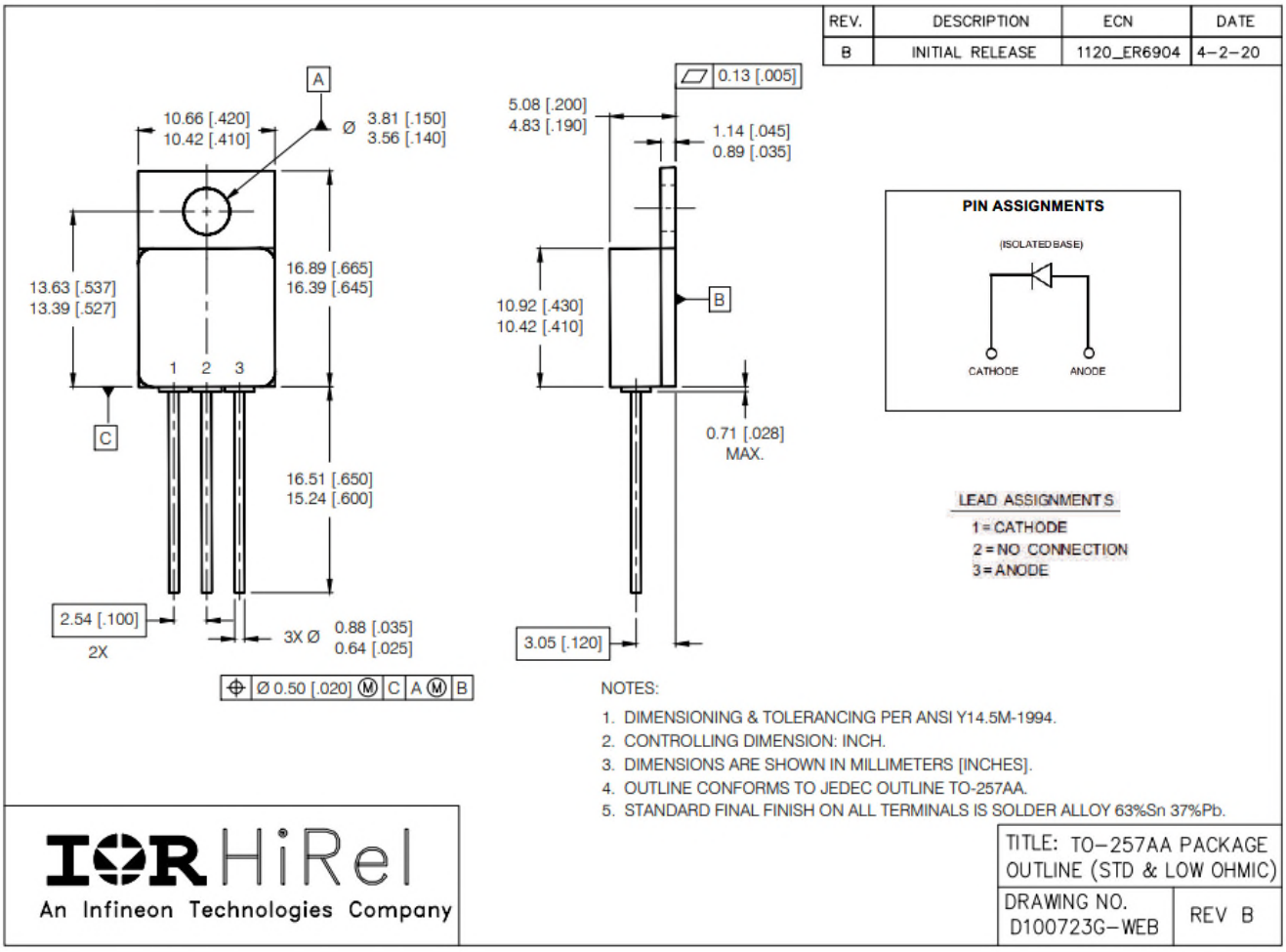


Figure 10 Reverse Recovery Waveform and Definitions

5 Package Outline

Note: For the most updated package outline, please see the website: TO-257AA



Revision history

Document version	Date of release	Description of changes
	06/26/2001	Final datasheet (PD-94222)
Rev A	08/08/2001	Updated IR test condition
Rev B	08/02/2019	Updated per ECN-1120-07208
Rev C	05/02/2023	Updated per ECN-1120-09532

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